

Key Concepts for EE 452 Midterm

- Use correct units in all problems [V, A, W, J, s]
- Names of power semiconductor devices & their defining characteristics
- Ripple equations:

$$V_L \approx L \frac{\Delta i_L}{\Delta t}, \quad i_C \approx C \frac{\Delta V_C}{\Delta t} \quad \leftarrow \text{Evaluate in one ckt configuration.}$$

- Volt-second & Charge balance equations:

$$\langle V_L \rangle = 0 = D(V_L \text{ for configuration ①}) + D'(V_L \text{ for configuration ②})$$

$$\langle i_C \rangle = 0 = D(i_C \text{ for configuration ①}) + D'(i_C \text{ for configuration ②})$$

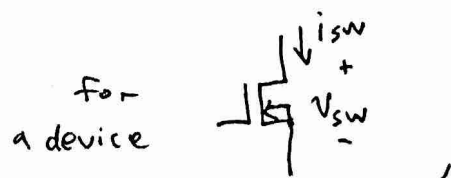
- Using balance equations, know how to obtain the following:

Know how to compute with loss mechanisms included (R_{on}, R_L, V_f)

- Voltage conversion ratio $M = \frac{V}{V_g}$
- Efficiency $\eta = \frac{P_{out}}{P_{in}}$
- Steady state inductor currents & cap voltages

↳ Apply to pick suitable devices

- Given device waveforms, compute switching energy & power loss



$$E_{loss} = \int_{T=t_0}^{T=t_{final}} V_{sw}(T) i_{sw}(T) dT$$

area under curve

$$P_{loss}^{sw} = F_{sw} E_{loss}$$

→ Know how η is impacted by P_{loss}^{sw} & F_{sw} .

EE 452 – Power Electronics Design, Autumn 2021
Midterm – Cover Page
 Friday November 5th 2021

Name: _____

Instructions. Show all your work and clearly indicate your final answer for each problem. When you are done, staple this cover sheet to your work.

Problem 1: Devices and component polarities [10 Points Total]

- (a) [6 Points] Write down the names for each of the red terminals in Figure 1, and highlight the regions each device can operate (excluding the body diode).

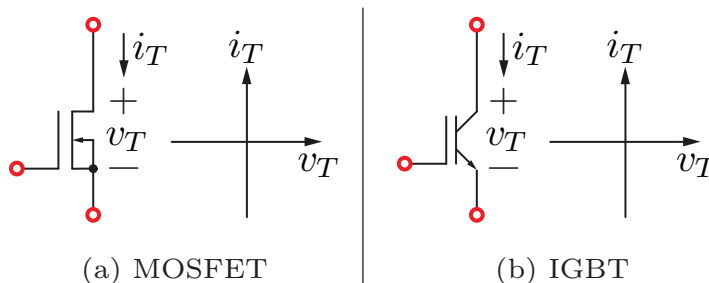


Figure 1: (a) MOSFET, and (b) IGBT.

- (b) [2 Points] Label the capacitor current, i_c , along with its direction in Figure 2(a).
 (c) [2 Points] Label the inductor voltage, v_L , along with its $+/-$ terminals in Figure 2(b).

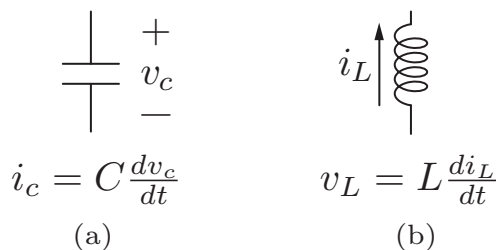


Figure 2: Draw the capacitor current in (a) and inductor voltage in (b).

Problem 2: Steady-state converter analysis. [60 Points Total]

Consider the converter below where the inductor has winding resistance R_L . All other components are ideal. Use the small-signal approximation for all analysis below.

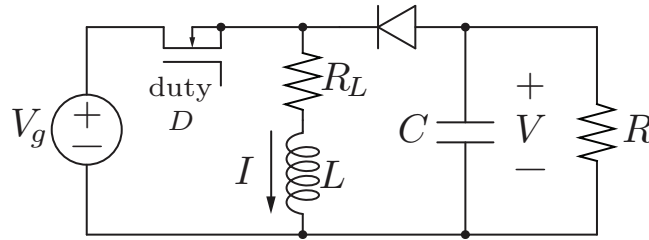


Figure 3: Converter for Problem 2.

- (a) [5 Points] What is the name of the converter in Figure 3?
- (b) [5 Points] Derive the Volt-second balance equation.
- (c) [5 Points] Derive the charge balance equation.
- (d) [10 Points] Solve for the inductor current I in terms of V , R , D , and $D' = 1 - D$.

(e) **[10 Points]** Compute the conversion ratio $M := V/V_g$ in terms of R_L, R, D , and $D' = 1 - D$.

(f) **[10 Points]** Compute the efficiency η in terms of R_L, R, D , and $D' = 1 - D$.

(g) **[15 Points]** Use your result from parts (d)–(e) and the numerical values below. Compute the critical switching frequency, f_s , such that the inductor current dc component and ripple component are the same (i.e., $I = \Delta i$).

- $D = 0.5$, $R = 10\ \Omega$, $R_L = 0.1\ \Omega$, $L = 100\ \mu\text{H}$

Problem 3: Switching loss analysis [30 Points Total]

Consider the switch transition waveforms for an IGBT. The waveforms and device quantities are shown in Figure 4.

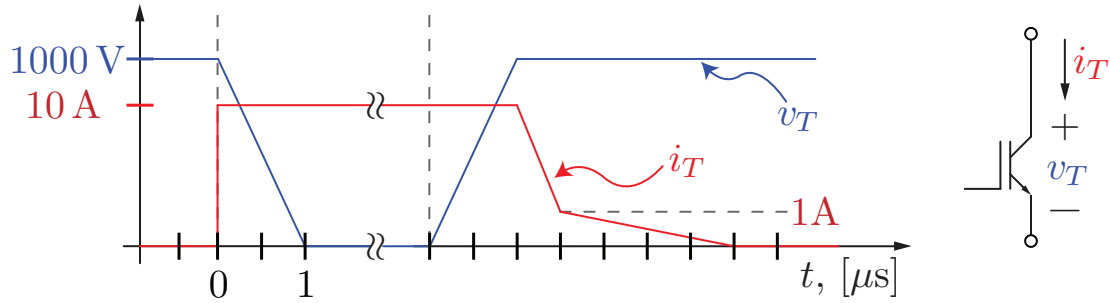


Figure 4: IGBT waveforms for Problem 3.

- (a) **[10 Points]** Draw the waveform of the power dissipated in the IGBT. Use the blank plot provided below.

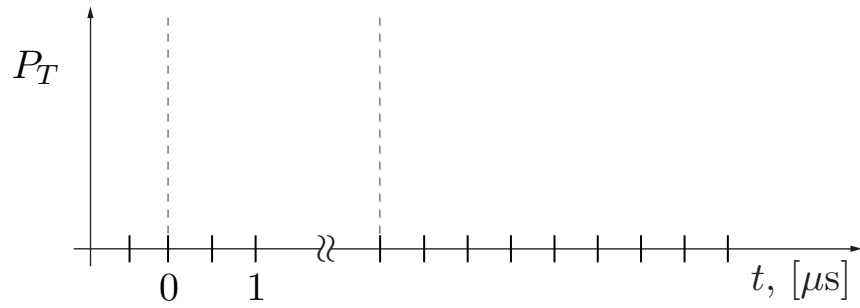


Figure 5: Plot for Problem 3(a).

- (b) **[10 Points]** Compute the total energy dissipated during both switch transitions.

- (c) **[10 Points]** Neglecting all other sources of loss and assuming an input power of $P_{\text{in}} = 50 \text{ kW}$, compute the maximum switching frequency such that $\eta \geq 0.98$.

